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Kind regards,

Team Nexperia

PDTA144V series

PNP resistor-equipped transistors; $R1 = 47 \text{ k}\Omega$, $R2 = 10 \text{ k}\Omega$

Rev. 04 — 3 September 2009

Product data sheet

1. Product profile

1.1 General description

PNP resistor-equipped transistors.

Table 1. Product overview

Type number	Package		NPN complement
	NXP	JEITA	
PDTA144VE	SOT416	SC-75	PDTC144VE
PDTA144VK	SOT346	SC-59A	PDTC144VK
PDTA144VM	SOT883	SC-101	PDTC144VM
PDTA144VS ^[1]	SOT54	SC-43A	PDTC144VS
PDTA144VT	SOT23	-	PDTC144VT
PDTA144VU	SOT323	SC-70	PDTC144VU

[1] Also available in SOT54A and SOT54 variant packages (see [Section 2](#))

1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

1.3 Applications

- General purpose switching and amplification
- Inverter and interface circuits
- Circuit drivers

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-50	V
I_O	output current (DC)		-	-	-100	mA
$R1$	bias resistor 1 (input)		33	47	61	$\text{k}\Omega$
$R2/R1$	bias resistor ratio		0.17	0.21	0.26	

2. Pinning information

Table 3. Pinning

Pin	Description	Simplified outline	Symbol
SOT54			
1	input (base)		
2	output (collector)		
3	GND (emitter)		
SOT54A			
1	input (base)		
2	output (collector)		
3	GND (emitter)		
SOT54 variant			
1	input (base)		
2	output (collector)		
3	GND (emitter)		
SOT23, SOT323, SOT346, SOT416			
1	input (base)		
2	GND (emitter)		
3	output (collector)		
SOT883			
1	input (base)		
2	GND (emitter)		
3	output (collector)		

3. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
PDTA144VE	SC-75	plastic surface mounted package; 3 leads	SOT416
PDTA144VK	SC-59A	plastic surface mounted package; 3 leads	SOT346
PDTA144VM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm	SOT883
PDTA144VS ^[1]	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54
PDTA144VT	-	plastic surface mounted package; 3 leads	SOT23
PDTA144VU	SC-70	plastic surface mounted package; 3 leads	SOT323

[1] Also available in SOT54A and SOT54 variant packages (see [Section 2](#) and [Section 9](#)).

4. Marking

Table 5. Marking codes

Type number	Marking code ^[1]
PDTA144VE	13
PDTA144VK	12
PDTA144VM	E9
PDTA144VS	TA144V
PDTA144VT	*AG
PDTA144VU	*12

[1] * = -: made in Hong Kong
 * = p: made in Hong Kong
 * = t: made in Malaysia
 * = W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	-	-50	V
V _{CEO}	collector-emitter voltage	open base	-	-50	V
V _{EBO}	emitter-base voltage	open collector	-	-15	V
V _I	input voltage				
	positive		-	+15	V
	negative		-	-40	V
I _O	output current (DC)		-	-100	mA
I _{CM}	peak collector current		-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C			
	SOT416	[1]	-	150	mW
	SOT346	[1]	-	250	mW
	SOT883	[2][3]	-	250	mW
	SOT54	[1]	-	500	mW
	SOT23	[1]	-	250	mW
	SOT323	[1]	-	200	mW
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

[1] Refer to standard mounting conditions.

[2] Reflow soldering is the only recommended soldering method.

[3] Refer to SOT883 standard mounting conditions; FR4 printed-circuit board with 60 µm copper strip line.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	SOT416	[1]	-	-	833	K/W
	SOT346	[1]	-	-	500	K/W
	SOT883	[2][3]	-	-	500	K/W
	SOT54	[1]	-	-	250	K/W
	SOT23	[1]	-	-	500	K/W
	SOT323	[1]	-	-	625	K/W

[1] Refer to standard mounting conditions.

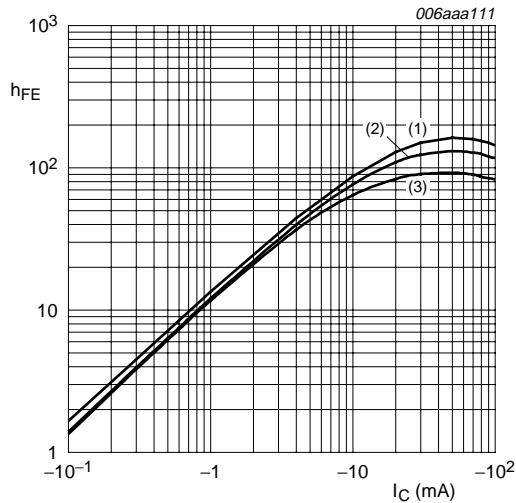
[2] Reflow soldering is the only recommended soldering method.

[3] Refer to SOT883 standard mounting conditions; FR4 printed-circuit board with 60 µm copper strip line.

7. Characteristics

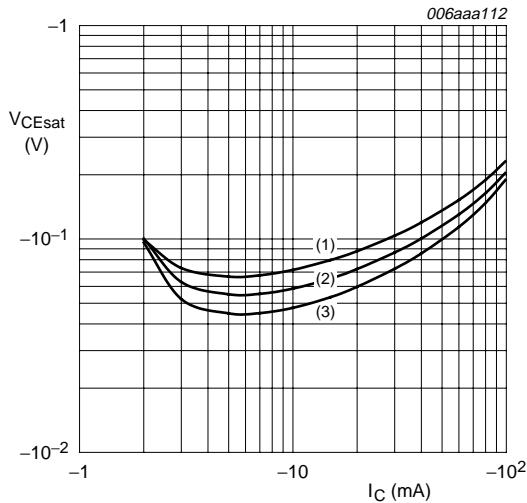
Table 8. Characteristics $T_{amb} = 25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CBO}	collector-base cut-off current	$V_{CB} = -50\text{ V}; I_E = 0\text{ A}$	-	-	-100	nA
I_{CEO}	collector-emitter cut-off current	$V_{CE} = -30\text{ V}; I_B = 0\text{ A}$	-	-	-1	μA
		$V_{CE} = -30\text{ V}; I_B = 0\text{ A}; T_j = 150^\circ\text{C}$	-	-	-50	μA
I_{EBO}	emitter-base cut-off current	$V_{EB} = -5\text{ V}; I_C = 0\text{ A}$	-	-	-150	μA
h_{FE}	DC current gain	$V_{CE} = -5\text{ V}; I_C = -5\text{ mA}$	40	-	-	
V_{CEsat}	collector-emitter saturation voltage	$I_C = -10\text{ mA}; I_B = -0.5\text{ mA}$	-	-	-150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = -5\text{ V}; I_C = -100\text{ μA}$	-	-3.1	-1	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = -300\text{ mV}; I_C = -2\text{ mA}$	-6	-3.8	-	V
R1	bias resistor 1 (input)		33	47	61	kΩ
R2/R1	bias resistor ratio		0.17	0.21	0.26	
C_c	collector capacitance	$V_{CB} = -10\text{ V}; I_E = i_e = 0\text{ A}; f = 1\text{ MHz}$	-	-	2	pF



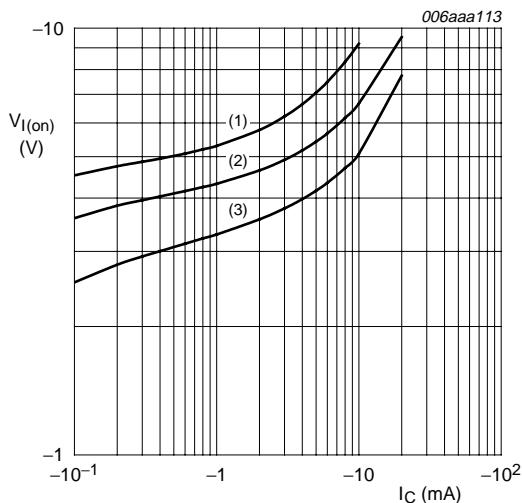
$V_{CE} = -5 \text{ V}$
(1) $T_{\text{amb}} = 100 \text{ }^{\circ}\text{C}$
(2) $T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$
(3) $T_{\text{amb}} = -40 \text{ }^{\circ}\text{C}$

Fig 1. DC current gain as a function of collector current; typical values



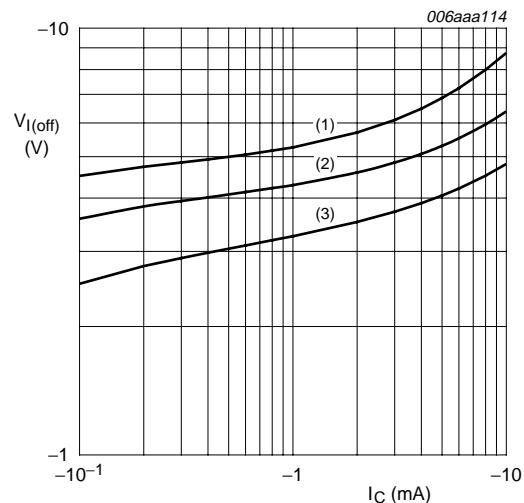
$|I_C/I_B| = 20$
(1) $T_{\text{amb}} = 100 \text{ }^{\circ}\text{C}$
(2) $T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$
(3) $T_{\text{amb}} = -40 \text{ }^{\circ}\text{C}$

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values



$V_{CE} = -0.3 \text{ V}$
(1) $T_{\text{amb}} = -40 \text{ }^{\circ}\text{C}$
(2) $T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$
(3) $T_{\text{amb}} = 100 \text{ }^{\circ}\text{C}$

Fig 3. On-state input voltage as a function of collector current; typical values



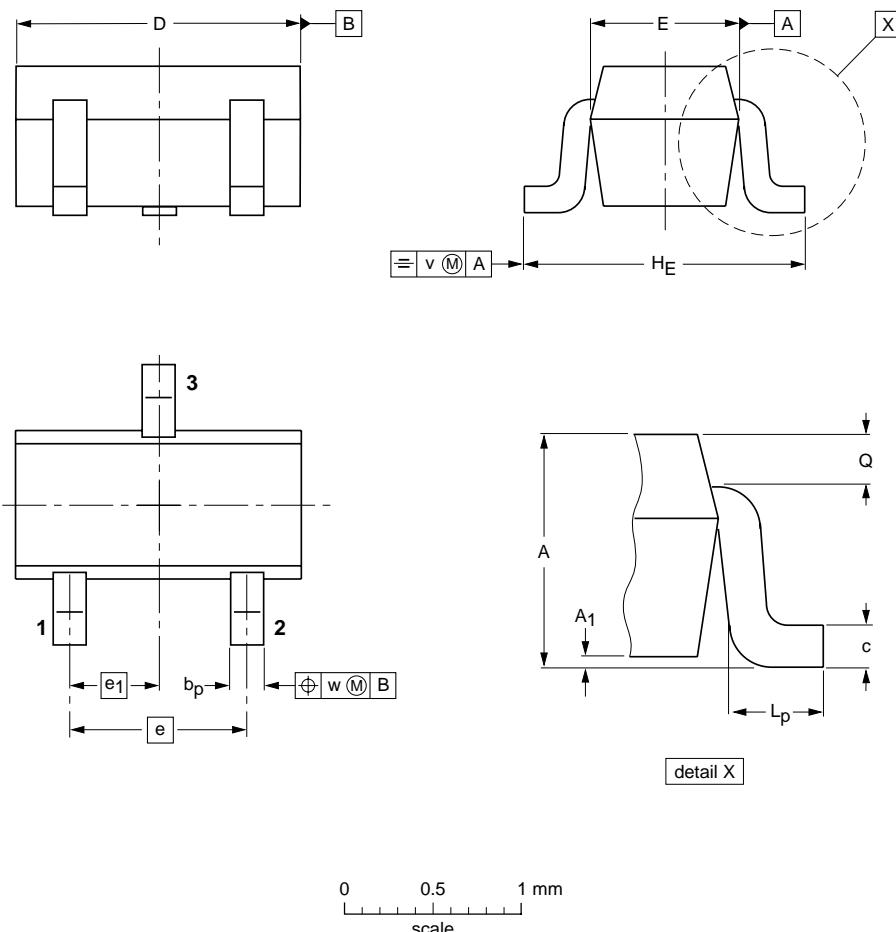
$V_{CE} = -5 \text{ V}$
(1) $T_{\text{amb}} = -40 \text{ }^{\circ}\text{C}$
(2) $T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$
(3) $T_{\text{amb}} = 100 \text{ }^{\circ}\text{C}$

Fig 4. Off-state input voltage as a function of collector current; typical values

8. Package outline

Plastic surface-mounted package; 3 leads

SOT416



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	0.95 0.60	0.1	0.30 0.15	0.25 0.10	1.8 1.4	0.9 0.7	1	0.5	1.75 1.45	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA	SC-75		
SOT416						-04-11-04- 06-03-16

Fig 5. Package outline SOT416 (SC-75)

Plastic surface-mounted package; 3 leads

SOT346

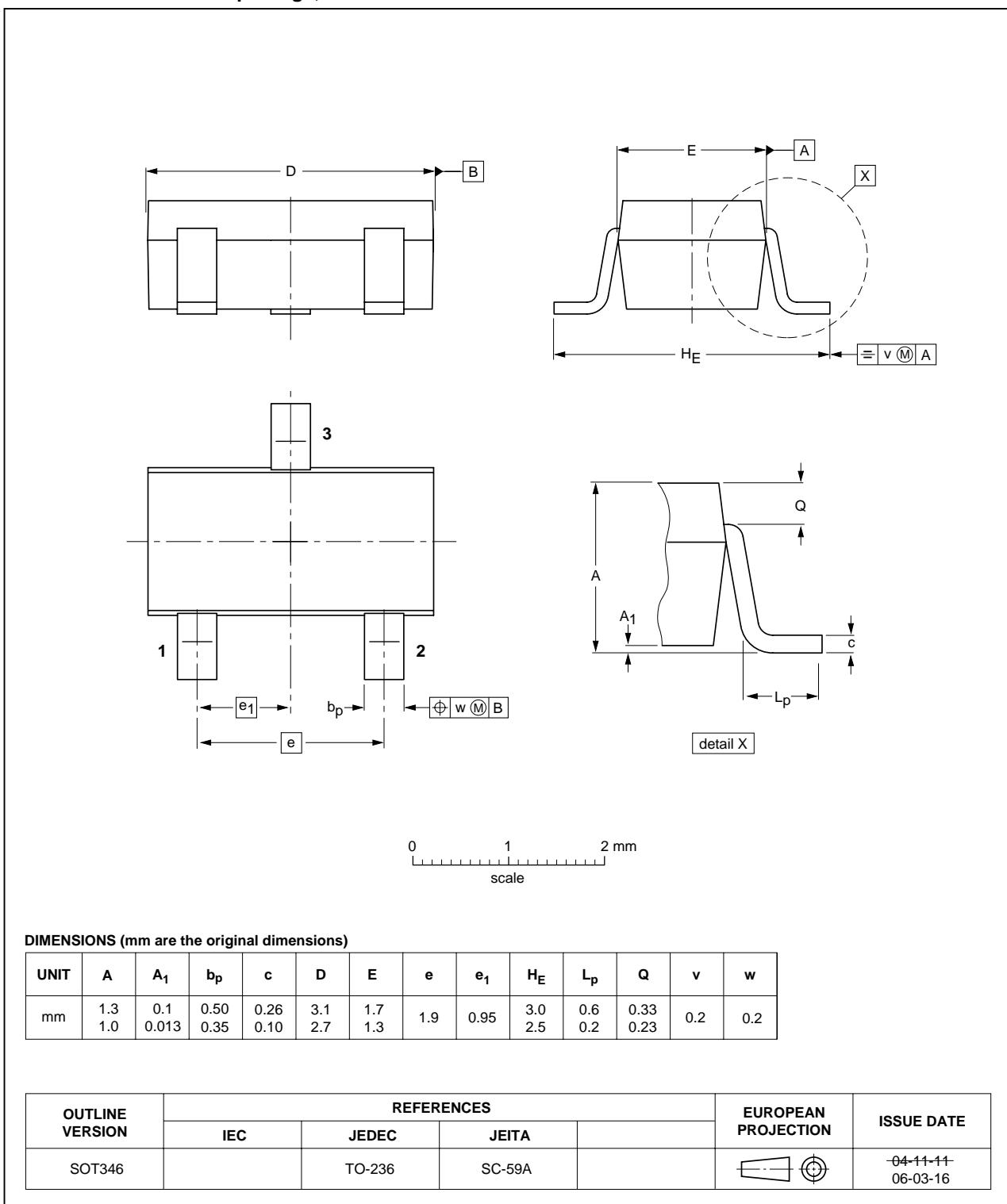


Fig 6. Package outline SOT346 (SC-59A/TO-236)

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

SOT883

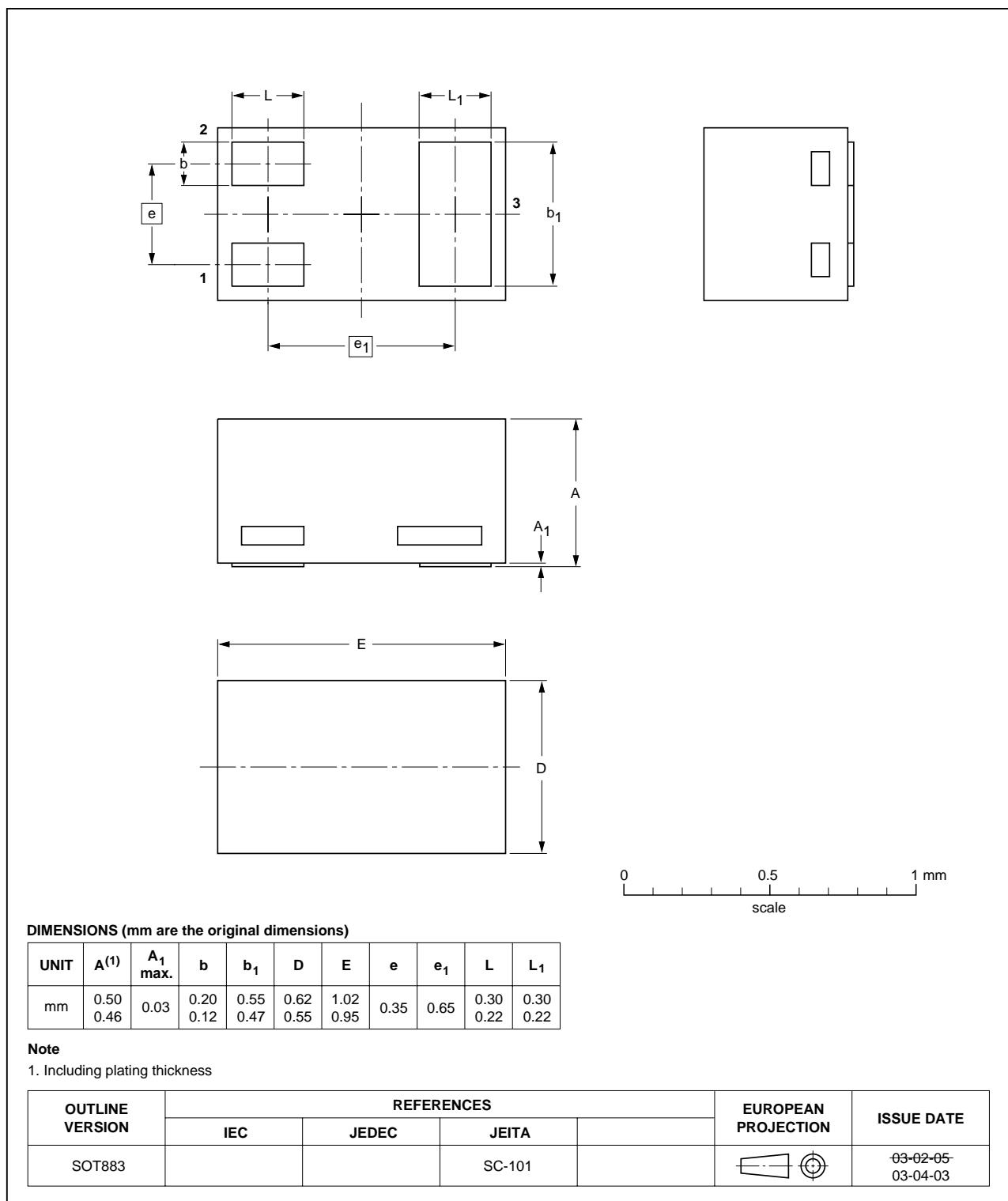


Fig 7. Package outline SOT883 (SC-101)

Plastic single-ended leaded (through hole) package; 3 leads

SOT54

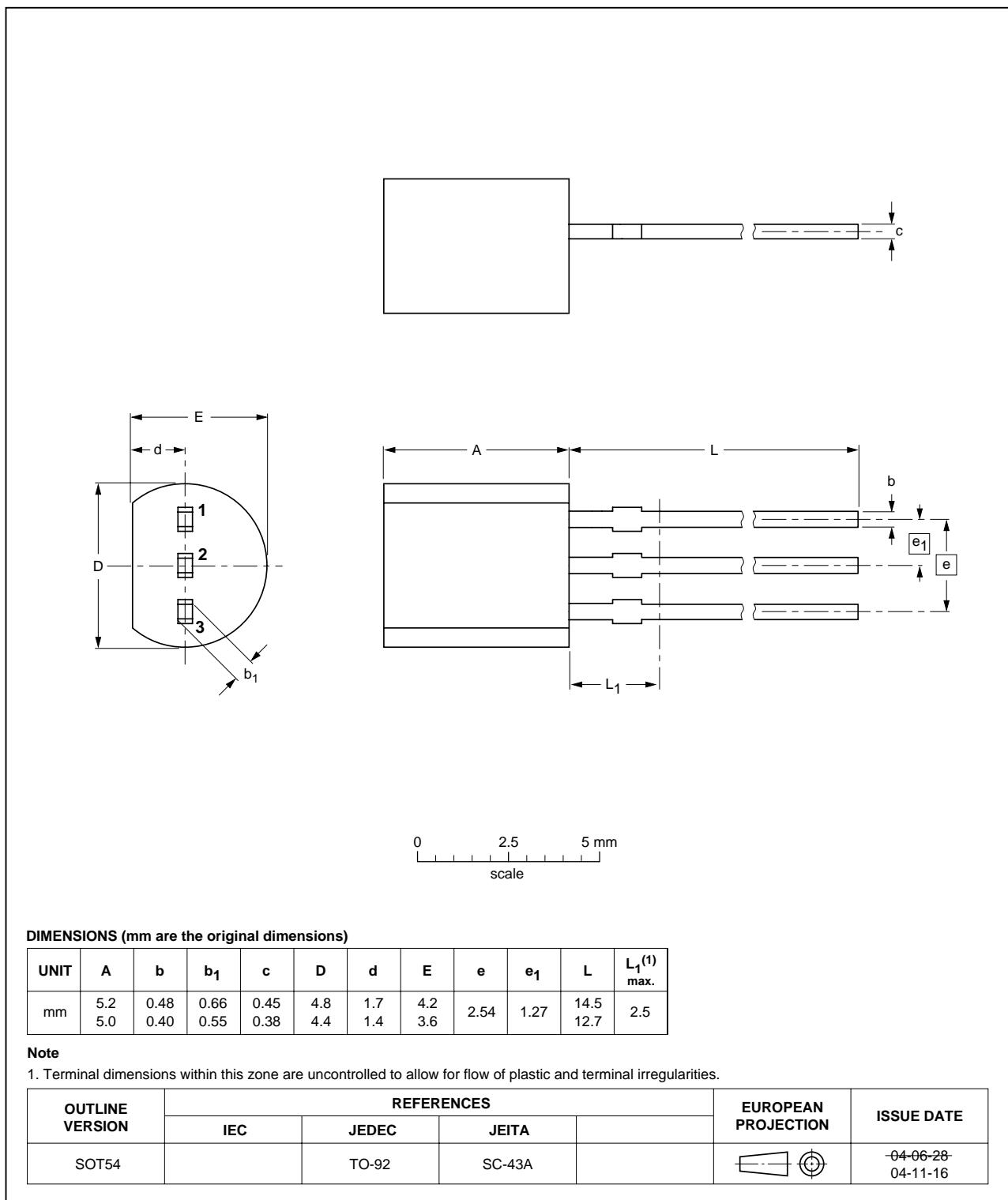


Fig 8. Package outline SOT54 (SC-43A/TO-92)

Plastic single-ended leaded (through hole) package; 3 leads (wide pitch)

SOT54A

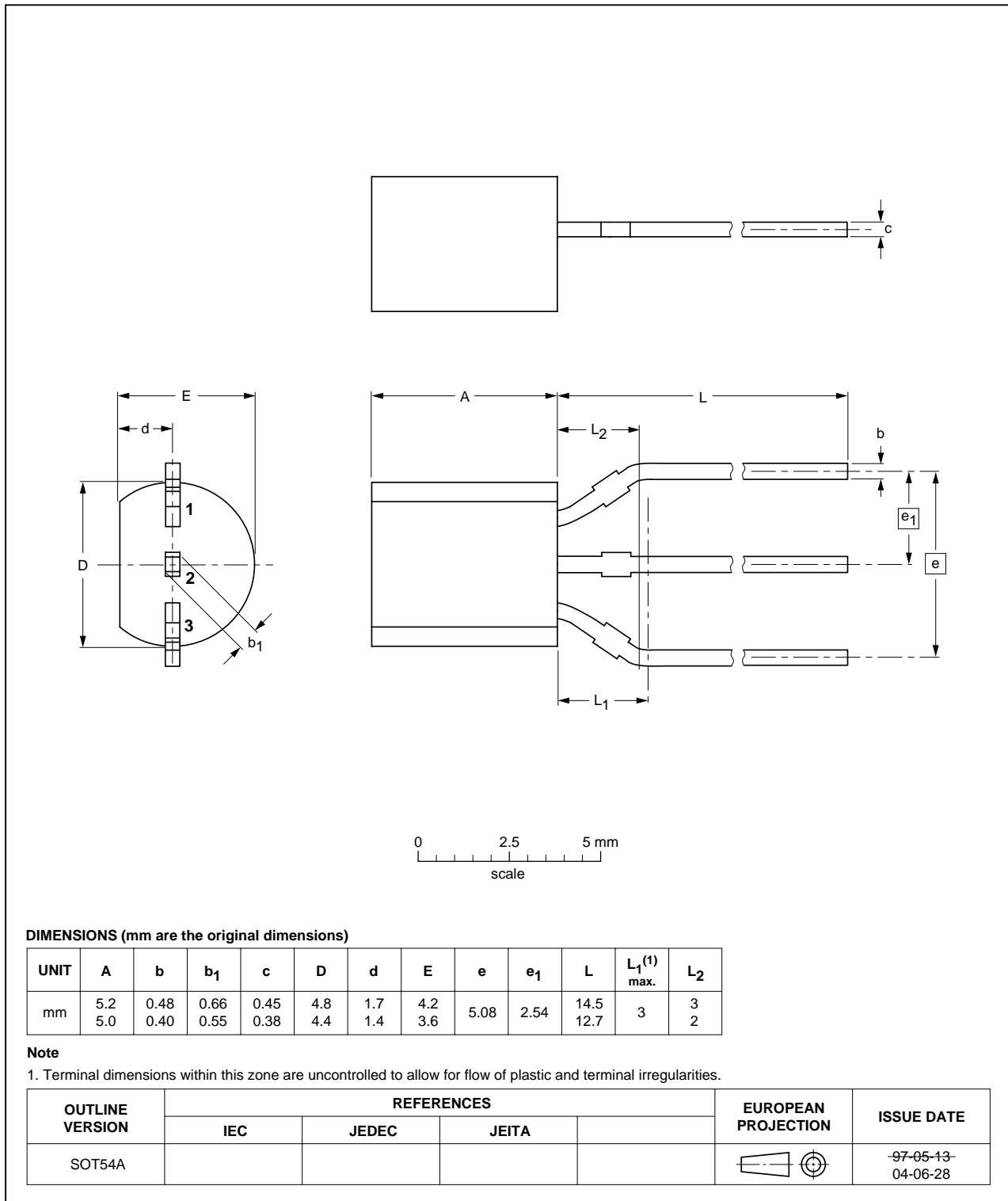


Fig 9. Package outline SOT54A

Plastic single-ended leaded (through hole) package; 3 leads (on-circle)

SOT54 variant

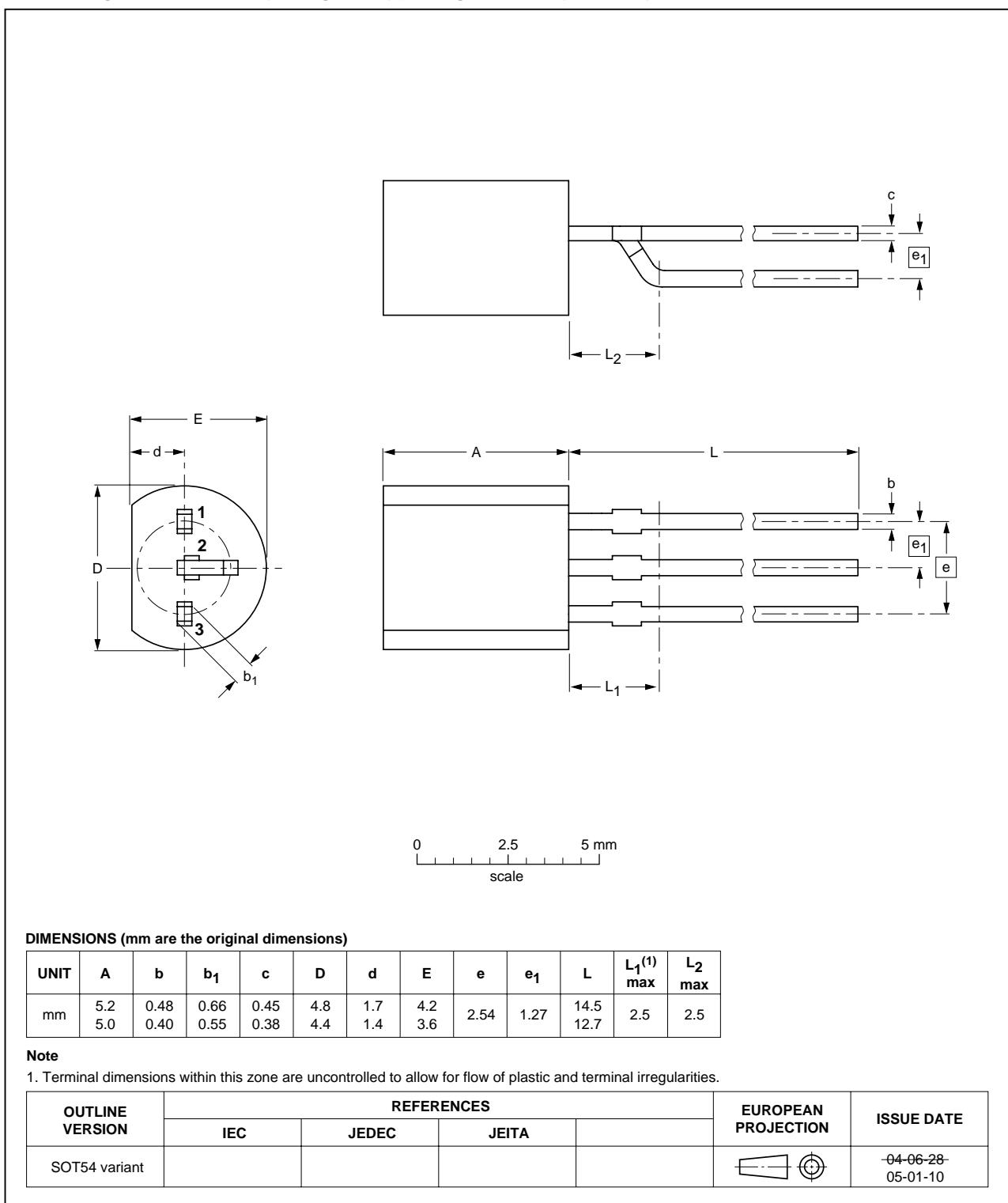


Fig 10. Package outline SOT54 variant

Plastic surface-mounted package; 3 leads

SOT23

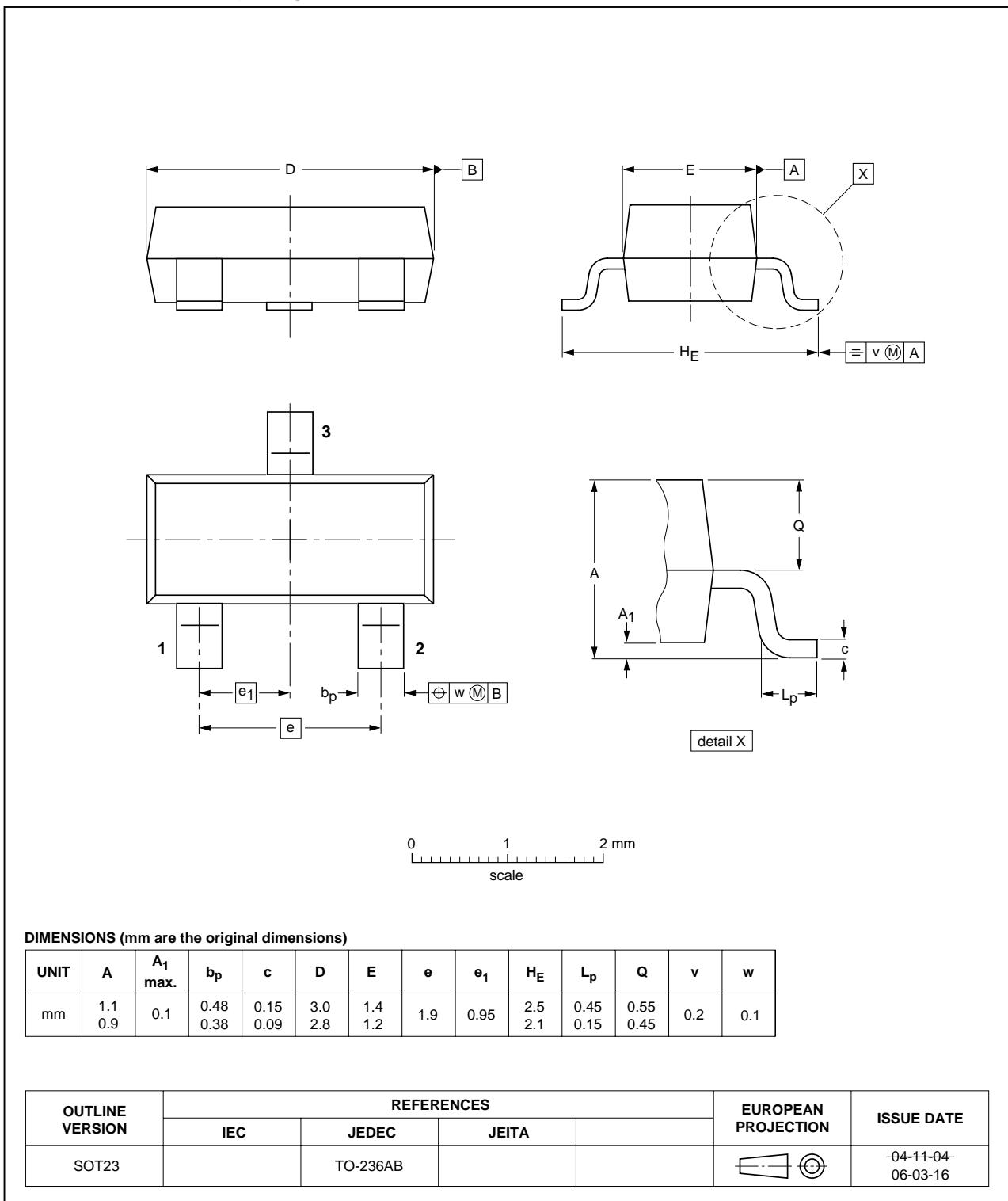
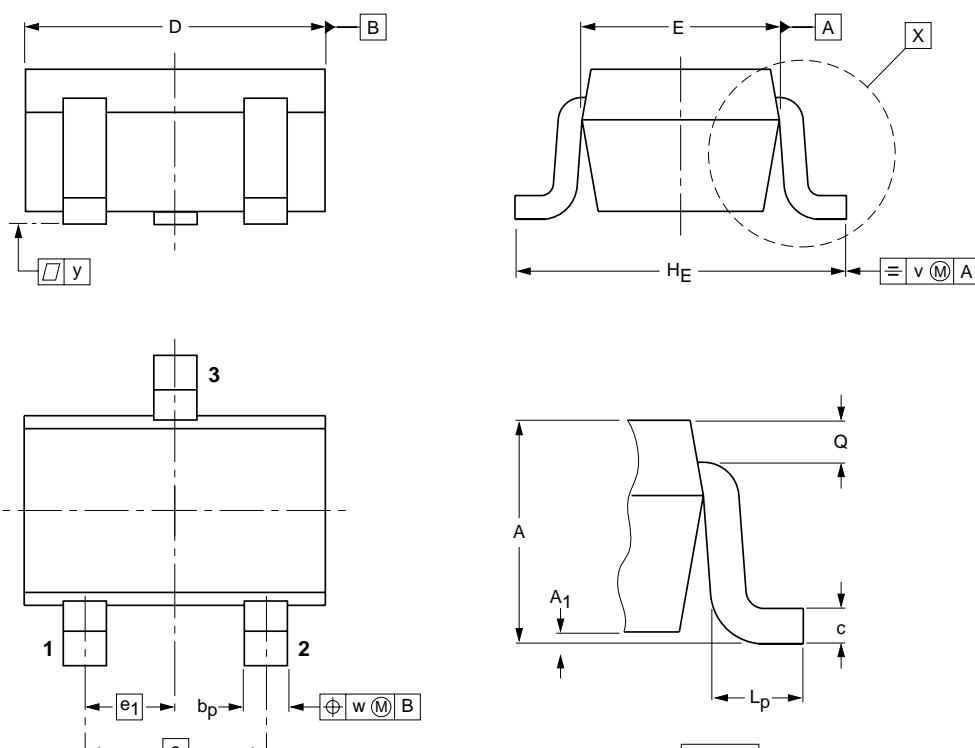


Fig 11. Package outline SOT23 (TO-236AB)

Plastic surface-mounted package; 3 leads

SOT323



0 1 2 mm
scale

DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT323			SC-70			-04-11-04- 06-03-16

Fig 12. Package outline SOT323 (SC-70)

9. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code. [1]

Type number	Package	Description	Packing quantity		
			3000	5000	10000
PDTA144VE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTA144VK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTA144VM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315
PDTA144VS	SOT54	bulk, straight leads	-	-412	-
	SOT54A	tape and reel, wide pitch	-	-	-116
		tape ammopack, wide patch	-	-	-126
		SOT54 variant	-	-112	-
PDTA144VT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235
PDTA144VU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135

[1] For further information and the availability of packing methods, see [Section 12](#).

10. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTA144V_SER_4	20090903	Product data sheet	-	PDTA144V_SER_3
Modifications:		<ul style="list-style-type: none">This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical contentFigure 5 "Package outline SOT416 (SC-75)": updatedFigure 6 "Package outline SOT346 (SC-59A/TO-236)": updatedFigure 11 "Package outline SOT23 (TO-236AB)": updatedFigure 12 "Package outline SOT323 (SC-70)": updated		
PDTA144V_SER_3	20050222	Product data sheet	-	PDTA144VT_2
PDTA144VT_2	20040514	Objective data sheet	-	PDTA144VT_1
PDTA144VT_1	20040305	Objective data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.